

DUAL TRANSISTOR (NPN+NPN)

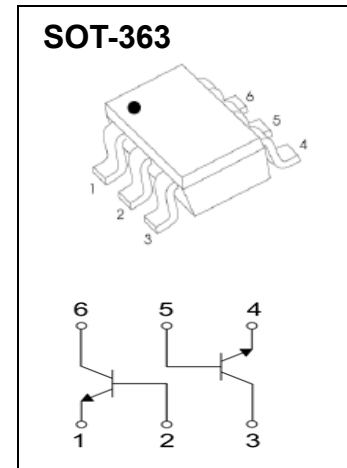
FEATURES

- Epitaxial planar die construction
- Ideal for low power amplification and switching

MARKING :K6N

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	40	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current -Continuous	0.2	A
P_C	Collector Power Dissipation	0.2	W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	$^{\circ}\text{C}$

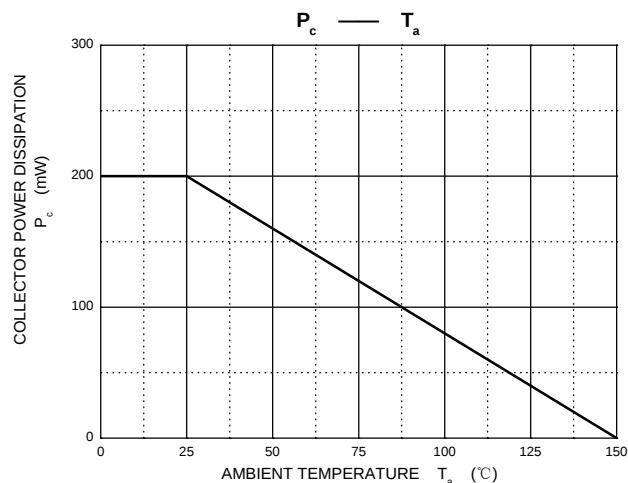
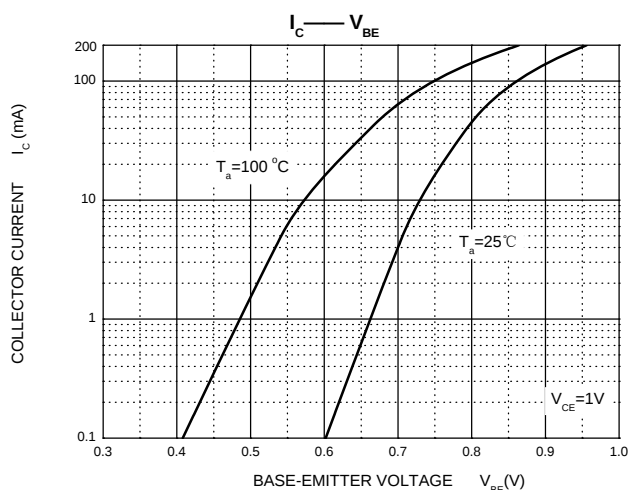
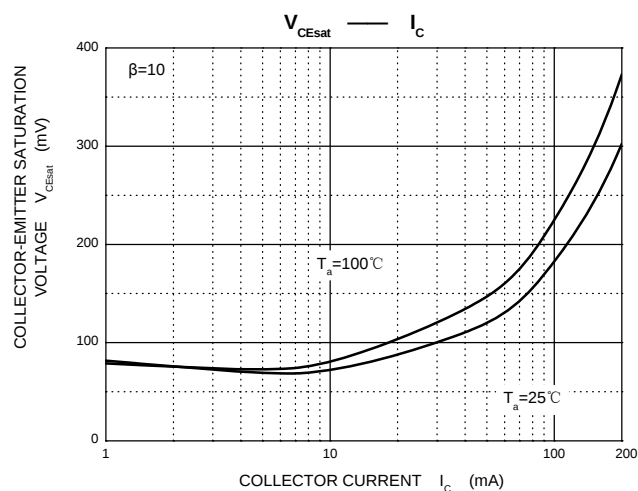
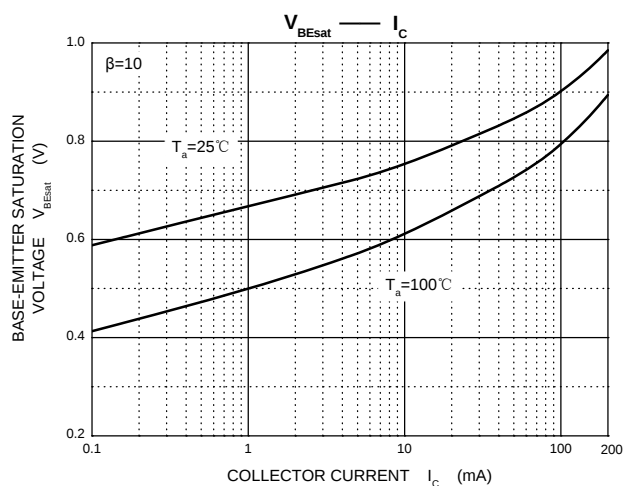
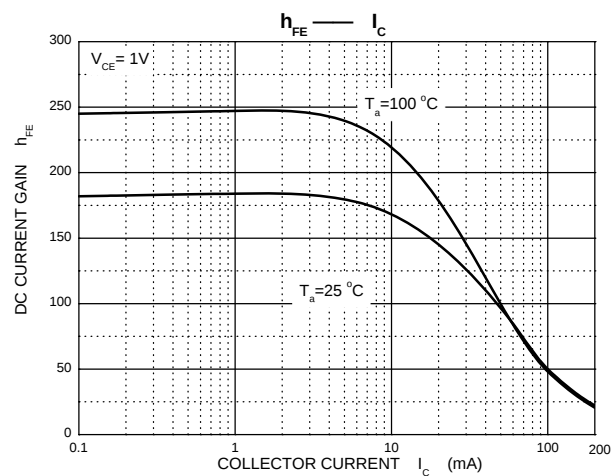
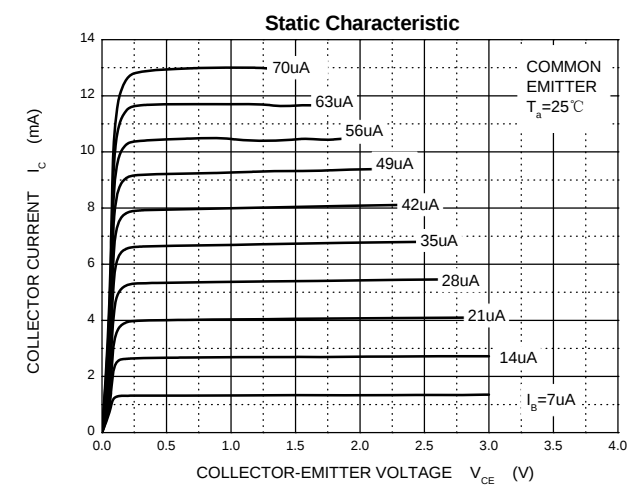


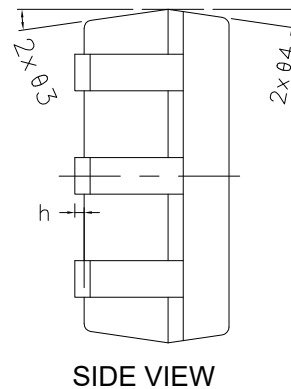
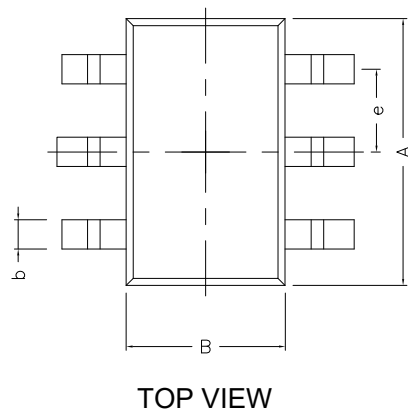
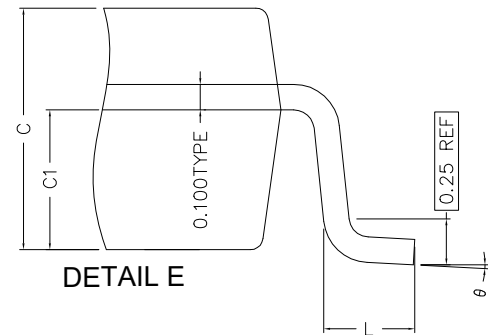
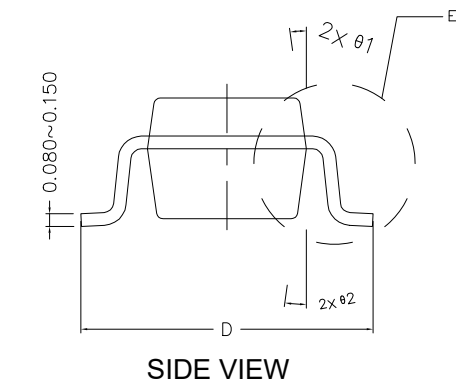
ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0$	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	40			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}=30\text{V}, I_E=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=5\text{V}, I_C=0$			0.1	μA
Collector cut-off current	I_{CEX}	$V_{CE}=30\text{V}, V_{BE(off)}=3\text{V}$			0.05	μA
DC current gain	$h_{FE(1)}$	$V_{CE}=1\text{V}, I_C=0.1\text{mA}$	40			
	$h_{FE(2)}$	$V_{CE}=1\text{V}, I_C=1\text{mA}$	70			
	$h_{FE(3)}$	$V_{CE}=1\text{V}, I_C=10\text{mA}$	100		300	
	$h_{FE(4)}$	$V_{CE}=1\text{V}, I_C=50\text{mA}$	60			
	$h_{FE(5)}$	$V_{CE}=1\text{V}, I_C=100\text{mA}$	30			
Collector-emitter saturation voltage	$V_{CE(sat)1}$	$I_C=10\text{mA}, I_B=1\text{mA}$			0.2	V
	$V_{CE(sat)2}$	$I_C=50\text{mA}, I_B=5\text{mA}$			0.3	V
Base-emitter saturation voltage	$V_{BE(sat)1}$	$I_C=10\text{mA}, I_B=1\text{mA}$	0.65		0.85	V
	$V_{BE(sat)2}$	$I_C=50\text{mA}, I_B=5\text{mA}$			0.95	V
Transition frequency	f_T	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	300			MHz
Collector output capacitance	C_{ob}	$V_{CB}=5\text{V}, I_E=0, f=1\text{MHz}$			4	pF
Noise figure	NF	$V_{CE}=5\text{V}, I_C=0.1\text{mA}, f=1\text{kHz}, R_S=1\text{K}\Omega$			5	dB
Delay time	t_d	$V_{CC}=3\text{V}, V_{BE(off)}=-0.5\text{V}$			35	nS
Rise time	t_r	$I_C=10\text{mA}, I_{B1}=-I_{B2}=1\text{mA}$			35	nS
Storage time	t_s	$V_{CC}=3\text{V}, I_C=10\text{mA}$			200	nS
Fall time	t_f	$I_{B1}=-I_{B2}=1\text{mA}$			50	nS



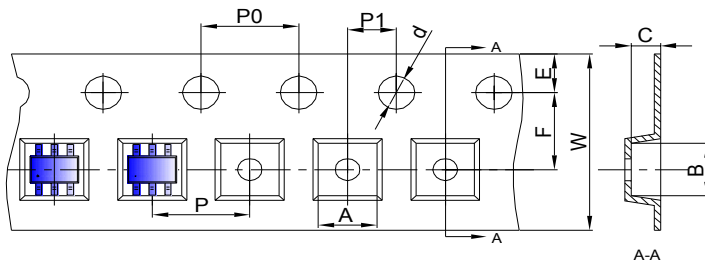
Typical Characteristics



**SOT-363 Package Outline Dimensions**

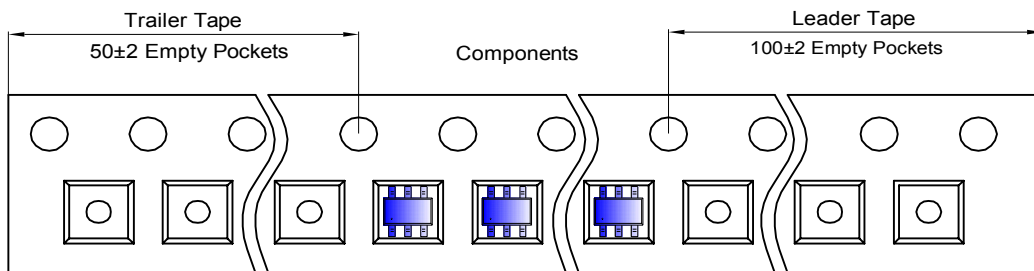
COMMON DIMENSIONS (UNITS OF MEASURE IS mm)			
	MIN	NORMAL	MAX
A	2.000	2.100	2.200
B	1.150	1.250	1.350
C	0.900	0.950	1.000
C1	0.500	0.550	0.600
D	2.100	2.300	2.500
L	0.220	0.360	0.500
b	0.200	0.250	0.400
h	0.020	0.050	0.100
e	0.650 TYPE		
θ ₁	8° TYPE		
θ ₂	8° TYPE		
θ ₃	8° TYPE		
θ ₄	8° TYPE		
θ	0~8° TYPE		

SOT-363 Embossed Carrier Tape

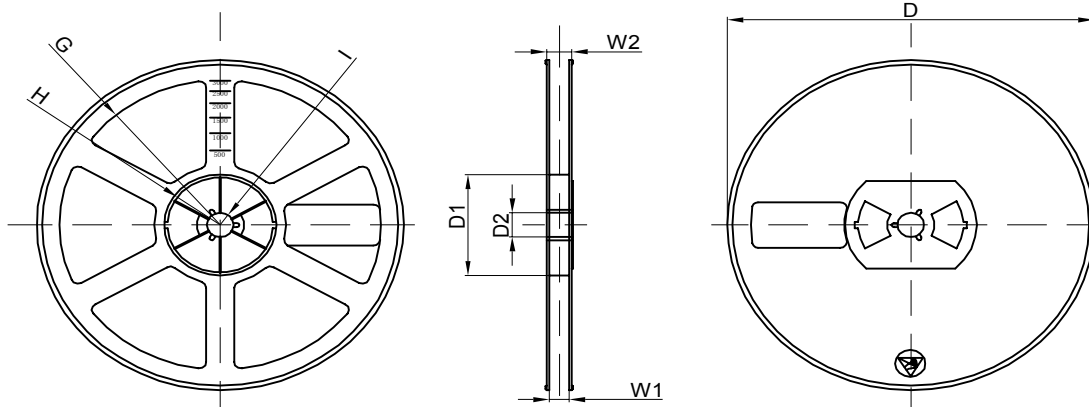


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-363	2.25	2.55	1.20	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-363 Tape Leader and Trailer



SOT-363 Reel



Dimensions are in millimeter							
Reel Option	D	D1	D2	G	H	I	W1
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	45,000 pcs	192x182x182	180,000 pcs	192x182x182	